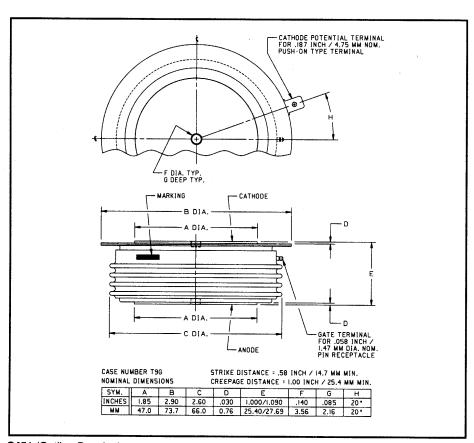


## Phase Control SCR 1500 Amperes Average 2400 Volts

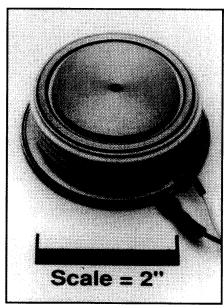


C451 (Outline Drawing)

## Ordering Information:

Select the complete five or six digit part number you desire from the table, i.e. C451LD is a 2400 Volt, 1500 Ampere Phase Control SCR.

	Volt	Current	
Туре	V <sub>DRM</sub> V <sub>RRM</sub>	Code	l <sub>T(av)</sub>
C451	1400	PD	1500
	1600	РМ	
•	1800	PN	
	2000	L	
	2200	LB	
	2400	LD	



**C451 Phase Control SCR** 1500 Amperes Average, 2400 Volts

### **Description:**

Powerex Silicon Controlled Rectifiers (SCR) are designed for phase control applications. These are all-diffused, Press-Pak, hermetic Pow-R-Disc devices employing the field proven amplifying gate.

#### Features:

- ☐ Low On-State Voltage
- ☐ High di/dt Capability
- ☐ High dv/dt Capability☐ Hermetic Packaging
- Excellent Surge and I<sup>2</sup>t Ratings

## **Applications:**

- Power Supplies
- VAR Generators



C451 Phase Control SCR 1500 Amperes Average, 2400 Volts

## **Absolute Maximum Ratings**

Characteristics	Symbol	C451	Units Volts	
Non-repetitive Transient Peak Reverse Voltage	V <sub>RSM</sub>	V <sub>RRM</sub> + 100V		
RMS On-state Current, T <sub>C</sub> = 64°C	I <sub>T(rms)</sub>	2350	Amperes	
Average Current 180° Sine Wave, T <sub>C</sub> = 64°C	I <sub>T(av)</sub>	1500	Amperes	
RMS On-state Current, T <sub>C</sub> = 55°C	lT(rms)	2590	Amperes	
Average Current 180° Sine Wave, T <sub>C</sub> = 55°C	I <sub>T(av)</sub>	1650	Amperes	
Peak One Cycle Surge On-state Current (Non-repetitive) 60Hz	l <sub>tsm</sub>	23000	Amperes	
Peak One Cycle Surge On-state Current (Non-repetitive) 50Hz	I <sub>tsm</sub>	20800	Amperes	
Critical Rate-of-rise of On-state Current (Non-repetitive)	di/dt	400	A/μsec	
Critical Rate-of-rise of On-state Current (Repetitive)	di/dt	75	A/μsec	
I <sup>2</sup> t (for Fusing) for One Cycle, 60Hz	ı <sup>2</sup> t	2.2 x 10 <sup>6</sup>	A <sup>2</sup> sec	
Peak Gate Power Dissipation	PGM	200	Watts	
Average Gate Power Dissipation	P <sub>G(av)</sub>	5	Watts	
Operating Temperature	T <sub>i</sub>	-40 to +125°C	°C	
Storage Temperature	T <sub>stg</sub>	-40 to +150°C	°C	
Approximate Weight		1	lb.	
		454	g	
Mounting Force		5500 to 6000	lb.	
		2450 to 2670	kg.	



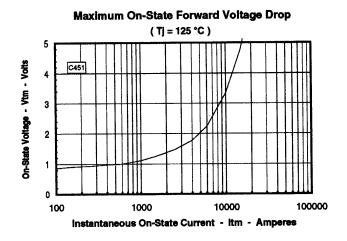
C451
Phase Control SCR
1500 Amperes Average, 2400 Volts

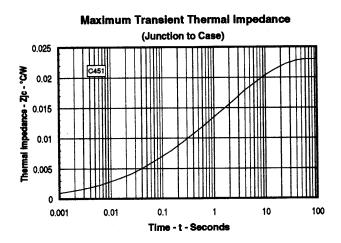
# Electrical Characteristics, $T_j = 25^{\circ}C$ Unless Otherwise Specified

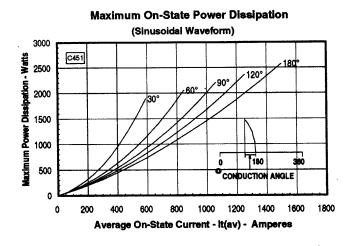
Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Repetitive Peak Reverse Leakage Current	IRRM	T <sub>i</sub> = 125°C, V <sub>R</sub> = V <sub>RRM</sub>	·		45	mA
Repetitive Peak Forward Leakage Current	IDRM	T <sub>j</sub> = 125°C, V <sub>D</sub> = V <sub>DRM</sub>			45	mA
Peak On-state Voltage	V <sub>TM</sub>	I <sub>TM</sub> = 3000A Peak			1.7	Volts
		Duty Cycle < 0.1%			•••	70.10
Threshold Voltage, Low-level	V <sub>(TO)1</sub>	$T_j = 125^{\circ}C$ , $I = 15\%$ , $I_{T(av)}$ to $\pi I_{T(av)}$			0.87956	Volts
Slope Resistance, Low-level	r <sub>T1</sub>	) (av)			0.2271	mΩ
Threshold Voltage, High-level	V <sub>(TO)2</sub>	$T_j = 125$ °C, $I = \pi I_{T(av)}$ to $I_{TSM}$			0.59931	Volts
Slope Resistance, High-level	rT2				0.2781	mΩ
V <sub>TM</sub> Coefficients, Low-level		$T_j = 125^{\circ}C$ , $I = 15\% I_{T(av)} to \pi I_{T(av)}$				
		, (2.,		A	1 = 0.839	82
				В	1 = 4.972	E-04
				С	1 = 2.032	E-04
V O-W-1-1-1-1				D	1 = 0.002	154
V <sub>TM</sub> Coefficients, High-level		$T_j = 125$ °C, $I = \pi I_{T(av)}$ to $I_{TSM}$				
					<sub>2</sub> = 12.127	
					2 = -1.809	
					2 = 1.429	
Torical Data T			· · · · · · · · · · · · · · · · · · ·	D	2 = 0.064	436
Typical Delay Time	<sup>t</sup> d	$I_T = 50A$ , Gate = 20V, $20\Omega$ ,		0.7		μsec
Typical Turn-off Time	•	0.1μsec Rise T <sub>i</sub> = 125°C, I <sub>T</sub> = 2000A,		450		
7,	<sup>t</sup> q	$di_{R}/dt = 25A/\mu sec Reapplied$		150		μsec
		dv/dt = 200V/μsec Linear to				
		$80\% V_{DRM}, V_{R} = 50V,$				
		Gate = 0V, $R_{GK} = 100\Omega$				
Minimum Critical dv/dt - Exponential to VDRM	dv/dt	T <sub>i</sub> = 125°C	400			Wusaa
Gate Trigger Current	<sup>I</sup> GT	T <sub>i</sub> = 25°C,			200	V/μsec mA
	G1	$V_D = 20V_{DC}$ , $R_L = 3\Omega$			200	ША
Gate Trigger Voltage	V <sub>GT</sub>	$T_i = -40^{\circ}\text{C to } +125^{\circ}\text{C},$			5.0	Volts
•	·Gi	$V_D = 20V$ , $R_L = 3\Omega$			5.0	VOILS
Non-Triggering Gate Voltage	V <sub>GDM</sub>	$T_i = 125^{\circ}C,$	<del></del>		0.45	14-11-
50, and contage	GDM	,			0.15	Volts
Peak Forward Gate Current	loma	$V_D = V_{DRM}, R_L = 1000\Omega$			40	
Peak Reverse Gate Voltage	IGTM				. 10	Α
- Jan 11070130 Gate Foliage	VGRM	<del></del>			5	Volts
Thermal Characteristics						
Maximum Thermal Resistance, Double Sided Co	oling					
Junction-to-Case	$R_{\theta(j-c)}$				0.025	°C/W
Case-to-Sink						
	R <sub>θ(c-s)</sub>				0.0075	°C/W

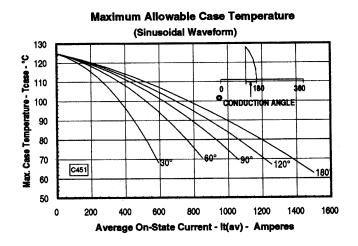


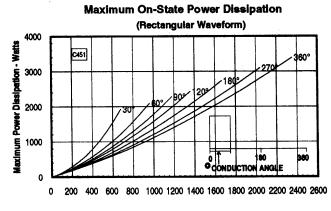
C451
Phase Control SCR
1500 Amperes Average, 2400 Volts

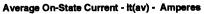


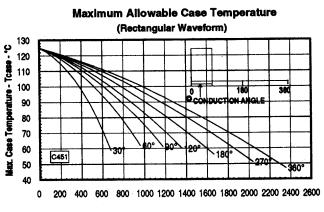












Average On-State Current - It(av) - Amperes